TRIPLE DIFFUSED PLANER TYPE HIGH VOLTAGE, HIGH SPEED SWITCHING

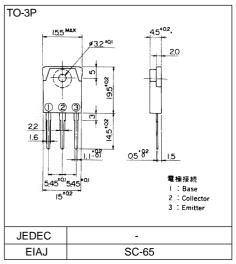
■ Features

- High voltage, High speed switching
- High reliability

Applications

- Switching regulators
- Ultrasonic generators
- High frequency inverters
- General purpose power amplifiers

■ Outline Drawings



■ Maximum ratings and characteristics

● Absolute maximum ratings (Tc=25°C unless otherwise specified)

Item	Symbol	Ratings	Unit
Collector-Base voltage	Vсво	450	V
Collector-Emitter voltage	VCEO	400	V
Collector-Emitter voltage	VCEO(SUS)	400	V
Emitter-Base voltage	Vево	7	V
Collector current	lc	10	Α
Base current	lB	3	Α
Collector power disspation	Pc	80	W
Operating junction temperature	Tj	+150	℃
Storage temperature	Tstg	-55 to +150	℃

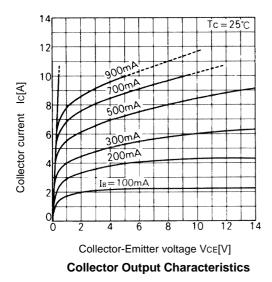
● Electrical characteristics (Tc =25°C unless otherwise specified)

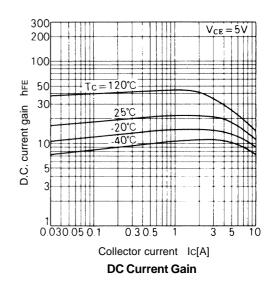
Item	Symbol	Test Conditions	Min.	Тур.	Max.	Units
Collector-Base voltage	Vсво	ICBO = 1mA	450			V
Collector-Emitter voltage	VCEO	ICEO = 10mA	400			V
Collector-Emitter voltage	VCEO(SUS)	Ic = 1A	400	-		V
Emitter-Base voltage	VEBO	IEBO = 0.1mA	7	-		V
Collector-Base leakage current	Ісво	VCBO = 450V		-	1.0	mA
Emitter-Base leakage current	I EBO	VEBO = 7V		-	0.1	mA
D.C. current gain	hFE	IC = 4A, VCE = 5V	10			
Collector-Emitter saturation voltage	VCE(Sat)	IC = 4A, IB = 0.8A			1.2	V
Base-Emitter saturation voltage	VBE(Sat)				1.5	V
*1	ton	Ic = 7.5A, IB1 = -IB2 = 1.5A			1.0	μs
Switching time	t stg	RL = 20 ohm ,Pw = 20µs Duty=<2%			2.0	μs
	tf				1.0	μs

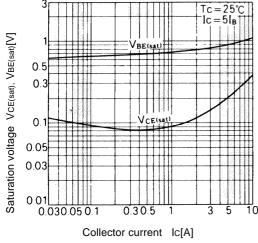
Thermal characteristics

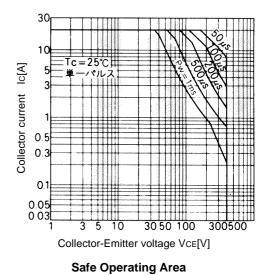
Item	Symbol	Test Conditions	Min.	Тур.	Max.	Units
Thermal resistance	Rth(j-c)	Junction to case			1.55	°C/W

Characteristics









Base and Collector Saturation Voltage



